

2-INPUT AND GATE

The KIC7S08FU is a high speed C²MOS 2-INPUT AND GATE fabricated with silicon gate C²MOS technology.

It achieves high speed operation similar to equivalent LSTTL while maintaining the C²MOS low power dissipation.

The internal circuit is composed of 2 stages including buffer output, which enables high noise immunity and stable output.

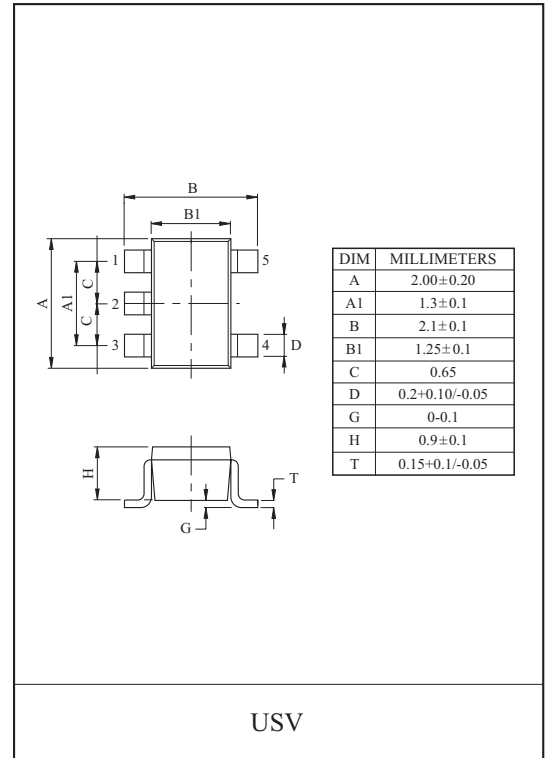
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES

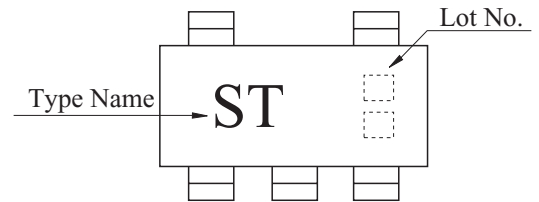
- High Speed : $t_{pd}=7ns(Typ.)$ at $V_{CC}=5V$.
- Low Power Dissipation : $I_{CC}=1 \mu A(Max.)$ at $T_a=25 \text{ }^\circ C$.
- High Noise Immunity : $V_{NIH}=V_{NIL}=28\% V_{CC}(Min.)$.
- Output Drive Capability : 5 LSTTL Loads.
- Symmetrical Output Impedance : $|I_{OH}|=I_{OL}=2mA(Min.)$
- Balanced Propagation Delays : $t_{pLH} \quad t_{pHL}$
- Wide Operating Voltage Range : $V_{CC(oper)}=2 \sim 6V$.

MAXIMUM RATINGS (Ta=25 °C)

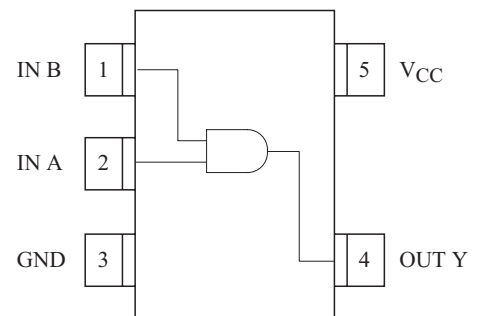
CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	-0.5 ~ 7	V
DC Input Voltage	V_{IN}	-0.5 ~ $V_{CC}+0.5$	V
DC Output Voltage	V_{OUT}	-0.5 ~ $V_{CC}+0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 12.5	mA
DC V_{CC} /Ground Current	I_{CC}	± 25	mA
Power Dissipation	P_D	200	mW
Storage Temperature	T_{stg}	-65 ~ 150	
Lead Temperature (10s)	T_L	260	



MARKING



PIN CONNECTION (TOP VIEW)



KIC7S08FU

LOGIC DIAGRAM



RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2 6	V
Input Voltage	V_{IN}	0 V_{CC}	V
Output Voltage	V_{OUT}	0 V_{CC}	V
Operating Temperature	T_{opr}	-40 85	
Input Rise and Fall Time	t_r, t_f	0 1000 ($V_{CC}=2.0V$) 0 500 ($V_{CC}=4.5V$) 0 400 ($V_{CC}=6.0V$)	ns

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION	V_{CC}	$T_a=25$			$T_a=-40 \quad 85$		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level Input Voltage	V_{IH}	-	2.0	1.5	-	-	1.5	-	V	
			4.5	3.15	-	-	3.15	-		
			6.0	4.2	-	-	4.2	-		
Low-Level Input Voltage	V_{IL}	-	2.0	-	-	0.5	-	0.5	V	
			4.5	-	-	1.35	-	1.35		
			6.0	-	-	1.8	-	1.8		
High-Level Output Voltage	V_{OH}	$V_{IN}=V_{IH}$	$I_{OH}=-20 \mu A$	2.0	1.9	2.0	-	1.9	-	V
				4.5	4.4	4.5	-	4.4	-	
				6.0	5.9	6.0	-	5.9	-	
			$I_{OH}=-2mA$ $I_{OH}=-2.6mA$	4.5	4.18	4.31	-	4.13	-	
			6.0	5.68	5.80	-	5.63	-		
Low-Level Output Voltage	V_{OL}	$V_{IN}=V_{IH}$ or V_{IL}	$I_{OL}=20 \mu A$	2.0	-	0.0	0.1	-	0.1	V
				4.5	-	0.0	0.1	-	0.1	
				6.0	-	0.0	0.1	-	0.1	
			$I_{OL}=2mA$ $I_{OL}=2.6mA$	4.5	-	0.17	0.26	-	0.33	
			6.0	-	0.18	0.26	-	0.33		
Input Leakage Current	I_{IN}	$V_{IN}=V_{CC}$ or GND	6.0	-	-	± 0.1	-	± 1.0	μA	
Quiescent Supply Current	I_{CC}	$V_{IN}=V_{CC}$ or GND	6.0	-	-	1.0	-	10.0		

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AC ELECTRICAL CHARACTERISTICS ($C_L=15\text{pF}$, Input $t_r=t_f=6\text{ns}$, $V_{CC}=5\text{V}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta=25			UNIT
			MIN.	TYP.	MAX.	
Output Transition Time	t_{TLH} t_{THL}	-	-	5	10	ns
Propagation Delay Time	t_{pLH} t_{pHL}	-	-	7	15	ns

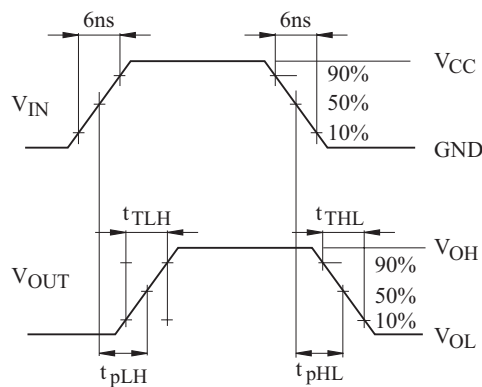
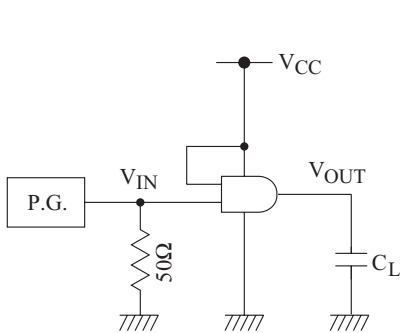
AC ELECTRICAL CHARACTERISTICS ($C_L=50\text{pF}$, Input $t_r=t_f=6\text{ns}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V_{CC}	Ta=25			Ta=-40 85		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	t_{TLH} t_{THL}	-	2.0	-	50	125	-	155	ns
			4.5	-	14	25	-	31	
			6.0	-	12	21	-	26	
Propagation Delay Time	t_{pLH} t_{pHL}	-	2.0	-	48	100	-	125	ns
			4.5	-	12	20	-	25	
			6.0	-	9	17	-	21	
Input Capacitance	C_{IN}	-	-	5	10	-	10	pF	
Power Dissipation Capacitance	C_{PD}	(Note 1)	-	10	-	-	-		

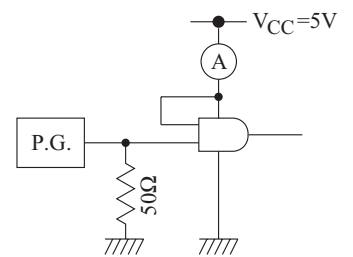
Note 1 : C_{PD} defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test Circuit.) Average operating current can be obtained by the equation hereunder.

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

SWITCHING CHARACTERISTICS TEST CIRCUIT



$I_{CC(opr)}$ TEST CIRCUIT



Input waveform is the same as that in case of switching characteristics test.